



**TET ESTEL AS
ESTONIA**

**April
2016**

**Series
D153-2500**

**Rectifier Press-Pack
Diode
Type D153-2500**

Designed for rectifiers and industrial applications

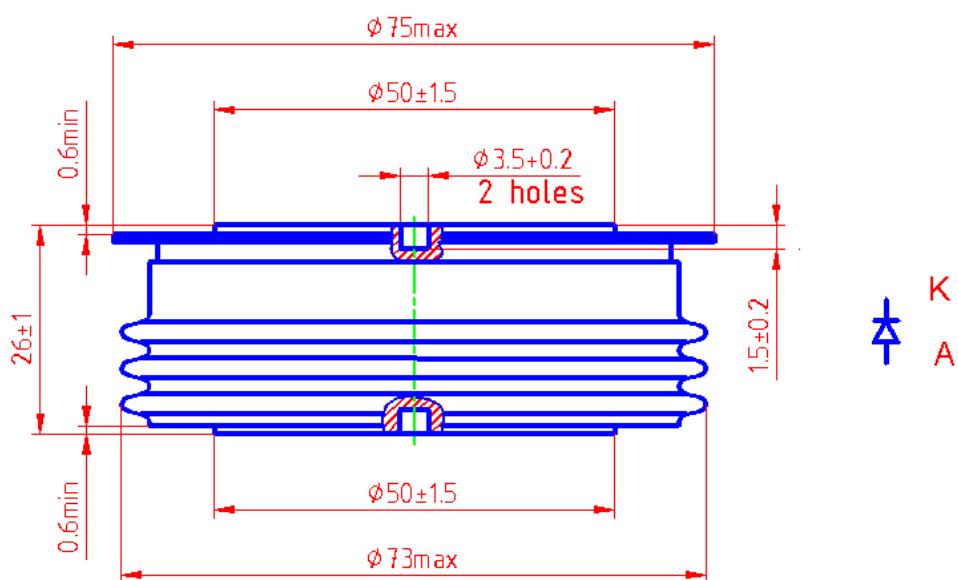
| | | |
|---|------------------|--------------|
| Maximum mean forward current | I _{FAV} | 2500 A |
| Maximum repetitive peak reverse voltage | U _{RRM} | 400 ÷ 1000 V |
| Reverse recovery time | trr (typ) | 20 μ s |
| U _{RRM} , V | 400 | 500 |
| Voltage code | 4 | 5 |
| Tvj, °C | - 60 ÷ 175 | |

| MAXIMUM ALLOWABLE RATINGS | | | | |
|----------------------------------|-------------------------------------|-------------------|--------------|---|
| Symbols and parameters | | Units | D153-2500 | Conditions |
| I _{FAV} | Mean forward current | A | 2500 4445 | Tc=118 °C, Tc=55 °C, 180° half-sine wave, 50 Hz |
| I _{FRMS} | RMS forward current | A | 3925 | Tc=118 °C |
| I _{FSM} | Surge forward current | kA | 37 40 | Tvj=175°C Tvj=25°C |
| I ² t | Limiting load integral | kA ² s | 6845 8000 | Tvj=175°C Tvj=25°C |
| U _{RRM} | Repetitive peak reverse voltage | V | 400÷1000 | Tj min≤Tvj≤Tj _M 180° half-sine wave, 50 Hz |
| U _{RSR} | Non-repetitive peak reverse voltage | V | 500÷1100 | Tj min≤Tvj≤Tj _M 180° half-sine wave tp=10 ms, Single pulse |
| T _{stg} | Storage temperature | °C | -60÷80 | |
| Tvj | Junction temperature | °C | -60÷175 | |
| CHARACTERISTICS | | | | |
| U _{FM} | Peak forward voltage | V | 1,5 1,45 | Tvj=25°C, I _{TM} =3,14 I _{AV} I _{TM} =6280A |
| U _{F(TO)} | Threshold voltage | V | 0,8 | Tvj=175°C 1,57 I _{AV} < I _T <4,71 I _{AV} |
| R _T | Forward slope resistance | mΩ | 0,05 | |
| I _{RRM} | Repetitive peak reverse current | mA | 75 | Tvj=175°C, UR= U _{RRM} |

| CHARACTERISTICS | | | | |
|------------------------|-------------------------------------|-------|-----------|--|
| Symbols and parameters | | Units | D153-2500 | Conditions |
| Qrr | Recovered charge (typ) | µC | 1400 | Tvj=175°C If=2500 A diR/dt =10 A/µs UR=100V |
| trr | Reverse recovery time (typ) | µs | 20 | |
| IrrM | Peak reverse recovery current (typ) | A | 140 | |
| Rthjc | Thermal resistance junction to case | °C/W | 0,02 | |
| | | | | Direct current, double side cooled |

| ORDERING | | | | |
|----------|---|-----|------|----|
| | D | 153 | 2500 | 10 |
| | 1 | 2 | 3 | 4 |

1. Diode
2. Design version
3. Mean forward current, A
4. Voltage code (10=1000 V)



Mounting force : 19 ÷ 28 kN
Weight : 580 grams